## NSN 5962-01-371-3176

Memory Microcircuit - Page 1 of 1



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Features Provided:
Programmed and electrostatic sensitive and w/clock and w/enable and monolithic
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Current Rating Per Characteristic:
190.00 milliamperes reverse current, dc absolute
Product Name:
Registered and-or gate array
Time Rating Per Chacteristic:
20.00 nanoseconds propagation delay
Memory Device Type:
Pal
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0